

Growth surface morphology, and electrical resistivity of fully strained substoichiometric epitaxial TiN_x ($0.67 \leq x < 1.0$) layers on $\text{MgO}(001)$

Shin, C.-S.; **Rudnja, Sergei**; Gall, D.; Hellgren, N.; Lee, T.-Y.; Petrov, I.; Greene, J.E. Journal of applied physics 2004 / 1, p. 356-362
: ill